

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## **DSA30C200IB**

preliminary

 $V_{RRM} = 200V$ 

 $I_{FAV} = 2x \quad 15A$ 

 $V_F = 0.78V$ 

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

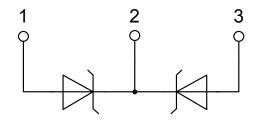
Schottky Diode Gen<sup>2</sup>

Part number

**DSA30C200IB** 



Backside: cathode



### Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-262 (I2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0





preliminary

Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse block	ing voltage	$T_{VJ} = 25^{\circ}C$			200	V
V <sub>RRM</sub>	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			200	V
I <sub>R</sub>	reverse current, drain current	V <sub>R</sub> = 200 V	$T_{VJ} = 25^{\circ}C$			250	μΑ
		$V_R = 200 V$	$T_{VJ} = 125^{\circ}C$			2.5	mΑ
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 15 A	$T_{VJ} = 25^{\circ}C$			0.94	V
		$I_F = 30 \text{ A}$				1.10	V
		I <sub>F</sub> = 15 A	T <sub>VJ</sub> = 125°C			0.78	V
		$I_F = 30 \text{ A}$				0.95	V
I <sub>FAV</sub>	average forward current	T <sub>c</sub> = 155°C	T <sub>vJ</sub> = 175°C			15	Α
		rectangular d = 0.5					 
V <sub>F0</sub>	threshold voltage $T_{vJ} = 175^{\circ}C$				0.53	V	
r <sub>F</sub>	slope resistance				10.8	mΩ	
R <sub>thJC</sub>	thermal resistance junction to cas	e				1.75	K/W
R <sub>thCH</sub>	thermal resistance case to heatsin	nk			0.50		K/W
P <sub>tot</sub>	total power dissipation		$T_{c} = 25^{\circ}C$			85	W
I <sub>FSM</sub>	max. forward surge current $t = 10 \text{ ms}$ ; (50 Hz), sine; $V_R = 0 \text{ V}$ $T_{VJ} = 45^{\circ}\text{C}$		$T_{VJ} = 45^{\circ}C$			320	Α
C¹	junction capacitance	V <sub>R</sub> = 48 V f = 1 MHz	$T_{VJ} = 25^{\circ}C$		47		pF

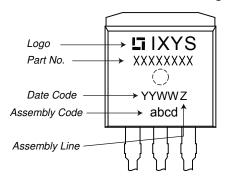


## **DSA30C200IB**

preliminary

Package TO-262 (I2Pak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal 1)			35	Α
T <sub>VJ</sub>	virtual junction temperature		-5	5	175	°C
T <sub>op</sub>	operation temperature		-5	5	150	°C
T <sub>stg</sub>	storage temperature		-5	5	150	°C
Weight				1.5		g
F <sub>c</sub>	mounting force with clip		2	כ	60	N

### **Product Marking**



#### Part number

D = Diode

S = Schottky Diode

A = low VF

30 = Current Rating [A]

C = Common Cathode

200 = Reverse Voltage [V] IB = TO-262 (I2Pak) (3)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA30C200IB	DSA30C200IB	Tube	50	512200

Similar Part	Package	Voltage class
DSA30C200PB	TO-220AB (3)	200

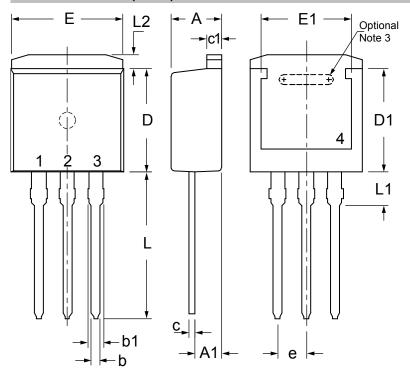
Equiva	alent Circuits for	Simulation	* on die level	T <sub>VJ</sub> = 175 °C
$I \rightarrow V_0$	$R_0$	Schottky		
V <sub>0 max</sub>	threshold voltage	0.53		V
$R_{0\text{max}}$	slope resistance *	7.6		$m\Omega$



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### Outlines TO-262 (I2Pak)



MYZ	INCHES		MILLIMETERS		
	MIN	MAX	MIN	MAX	
Α	160،	190،	4.06	4.83	
A1	.080	.110	2,03	2.79	
b	.025	.035	0.64	0.88	
b1	.025	.039	1.14	1.40	
С	.018	.025	0.46	0.64	
с1	.045	.055	1.14	1.40	
D	.340	.380	8,64	9,65	
D1	.270	.290	6.86	7.37	
Ε	.380	.405	9.65	10.29	
E1	.245	.320	6.22	8.13	
е	.100 BSC		2.54 BSC		
L	.500	.560	12.70	14.22	
L1	.100	.125	2.54	3.18	
L2	.040	.055	1.02	1,40	



NOTE:

- 1. This drawing will meet all dimensions requirement of JEDEC outline TO-262 AA.
- 2. All metal surface are matte pure tin plated except trimmed area.
- 3. Inter locking slot depends upon frame type.

